

GNSS LOW NOISE AMPLIFIER

■ GENERAL DESCRIPTION

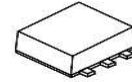
The NJG1144KA1 is a low noise amplifier GaAs MMIC designed for GNSS (Global Navigation Satellite Systems). This amplifier achieves high gain and a good balance between ultra-low noise figure and excellent VSWR, while low current consumption and high IP3, respectively.

The NJG1144KA1 operates from +1.5V to +3.6V supply voltage range and current consumes is as low as 3.5mA.

Also, the ESD protection circuit is integrated into the IC to achieve high ESD tolerance.

An ultra-small and easy mounting package of FLP6-A1 is adopted.

■ PACKAGE OUTLINE



NJG1144KA1

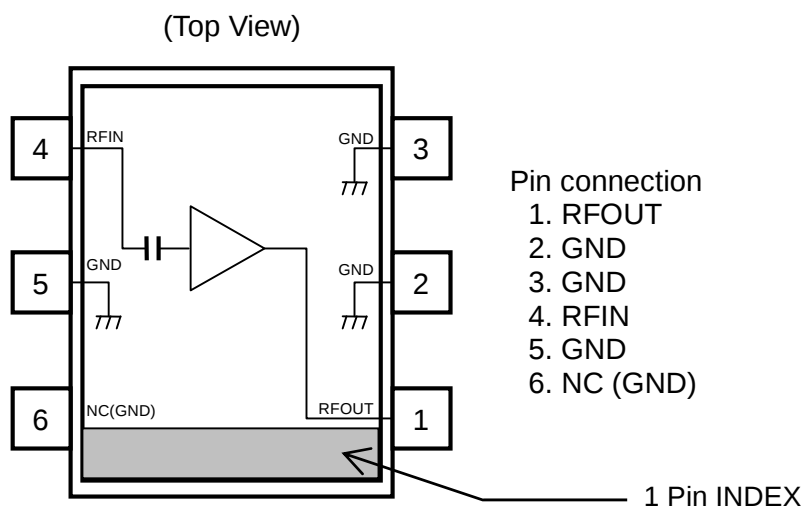
■ APPLICATIONS

GNSS applications, like GPS, Galileo, GLONASS and COMPASS.

■ FEATURES

- Low supply voltage 1.8V/2.85V
- Low current consumption 3.5mA typ. @ $V_{DD}=2.85V$
1.8mA typ. @ $V_{DD}=1.8V$
- High gain 21.0dB typ. @ $f=1575MHz$, $V_{DD}=2.85V$
- Low noise figure 0.65dB typ. @ $f=1575MHz$, $V_{DD}=2.85V$
- High Input IP3 -2.0dBm typ. @ $f=1575MHz$, $V_{DD}=2.85V$
- Small package FLP6-A1 (Package size: 1.6mm x 1.6mm x 0.55mm typ.)
- RoHS compliant and halogen free, MSL1

■ PIN CONFIGURATION



Note: Specifications and description listed in this datasheet are subject to change without notice.

■ ABSOLUTE MAXIMUM RATINGS

Ta=+25°C, Zs=Zl=50Ω

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V _{DD}		5.0	V
Input power	P _{IN}	V _{DD} =2.85V	+15	dBm
Power dissipation	P _D	4-layer FR4 PCB with through-hole (74.2mmx74.2mm), T _j =150°C	580	mW
Operating temperature	T _{opr}		-40 to +105	°C
Storage temperature	T _{stg}		-55 to +150	°C

■ ELECTRICAL CHARACTERISTICS 1 (DC CHARACTERISTICS)

General conditions: V_{DD}=2.85V, Ta=+25°C

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply voltage	V _{DD}		1.5	-	3.6	V
Supply current 1	I _{DD} 1	RF OFF, VDD=2.85V	-	3.5	5.5	mA
Supply current 2	I _{DD} 2	RF OFF, VDD=1.8V	-	1.8	3.2	mA

■ ELECTRICAL CHARACTERISTICS 2 (RF CHARACTERISTICS)

General conditions: $V_{DD}=2.85V$, $f_{RF}=1.575GHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small signal gain	Gain1		18.0	21.0	23.5	dB
Noise figure	NF1	Exclude PCB, Connector Losses(0.08dB)	-	0.65	0.95	dB
Input power at 1dB gain compression point 1	P-1dB(IN)1		-19.0	-16.5	-	dBm
Input 3rd order intercept point 1	IIP3_1	$f1=f_{RF}$, $f2=f1+100kHz$, $P_{in}=-34dBm$	-5.0	-2.0	-	dBm
RF input VSWR 1	VSWRi1		-	1.5	2.0	-
RF output VSWR 1	VSWRo1		-	1.5	2.0	-

■ ELECTRICAL CHARACTERISTICS 2 (RF CHARACTERISTICS)

General conditions: $V_{DD}=1.8V$, $f_{RF}=1.575GHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

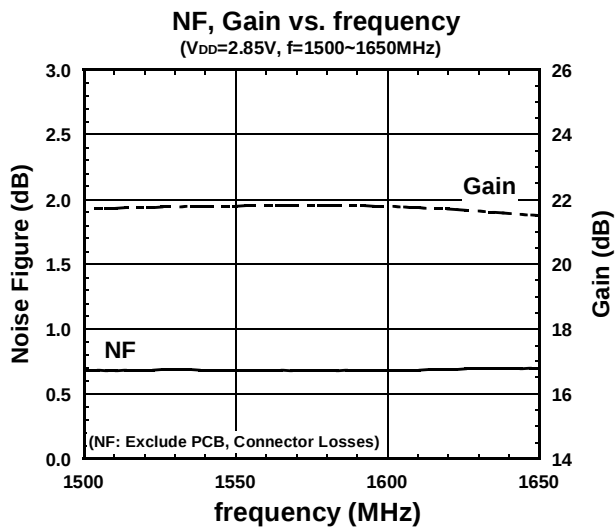
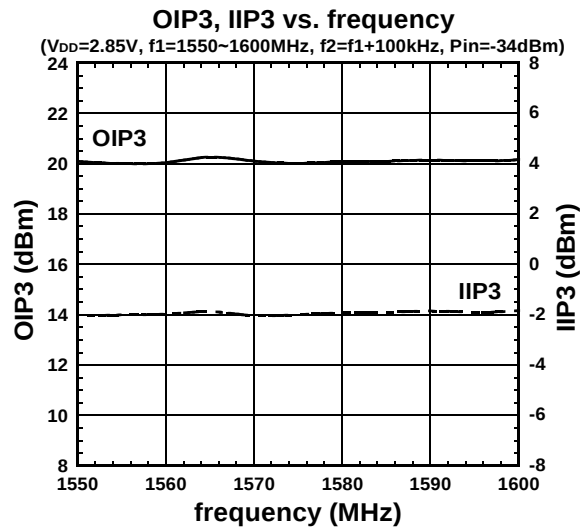
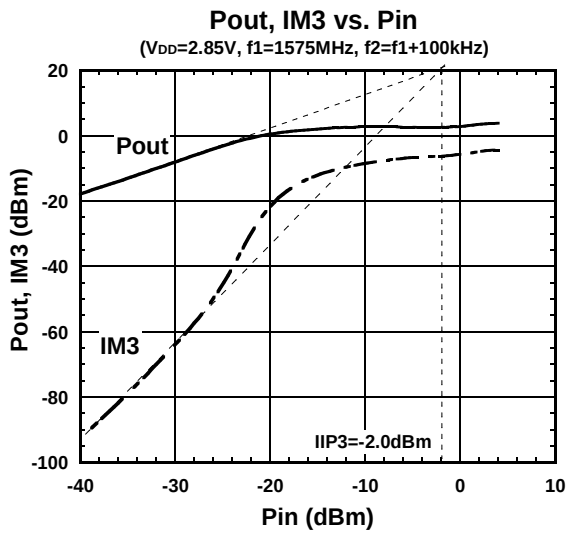
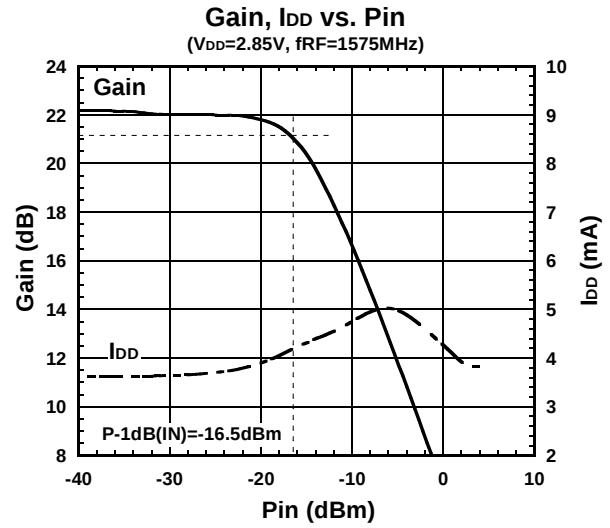
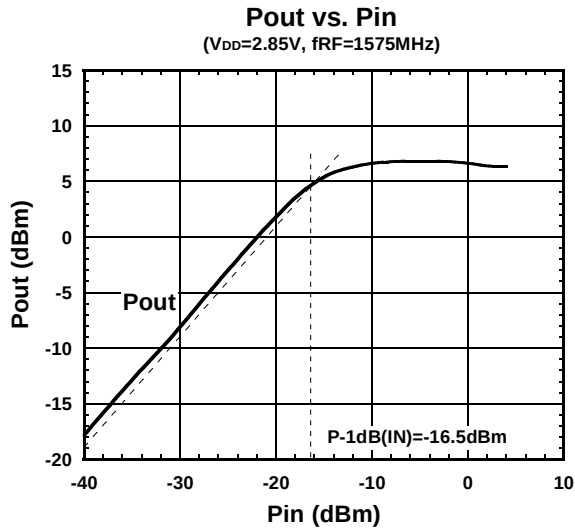
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small signal gain 2	Gain2		-	18.0	-	dB
Noise figure 2	NF2	Exclude PCB, Connector Losses(0.08dB)	-	0.85	-	dB
Input power at 1dB gain compression point 2	P-1dB(IN)2		-	-18.5	-	dBm
Input 3rd order intercept point 2	IIP3_2	$f1=f_{RF}$, $f2=f1+100kHz$, $P_{in}=-34dBm$	-	-6.0	-	dBm
RF input VSWR 2	VSWRi2		-	1.8	-	-
RF output VSWR 2	VSWRo2		-	1.8	-	-

■ TERMINAL INFORMATION

No.	SYMBOL	DESCRIPTION
1	RFOUT	RF output and voltage supply terminal.
2	GND	Ground terminal (0V), Connect to the PCB ground plane.
3	GND	Ground terminal (0V), Connect to the PCB ground plane.
4	RFIN	RF input terminal. DC blocking capacitor is not required. An external matching circuit is required.
5	GND	Ground terminal (0V), Connect to the PCB ground plane.
6	NC(GND)	No connected terminal. This terminal is not connected with internal circuit. Please connect to the PCB ground Plane.

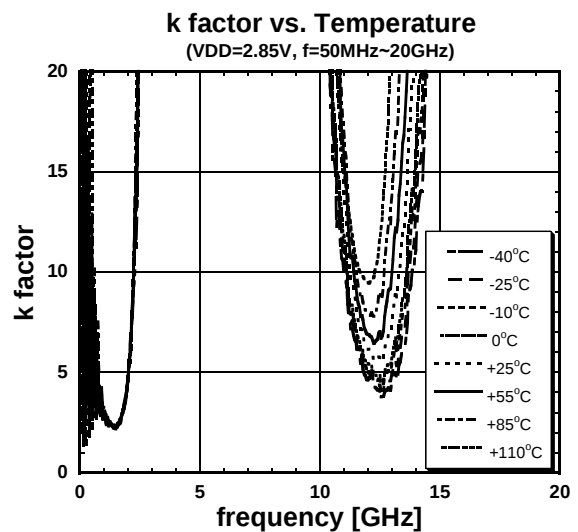
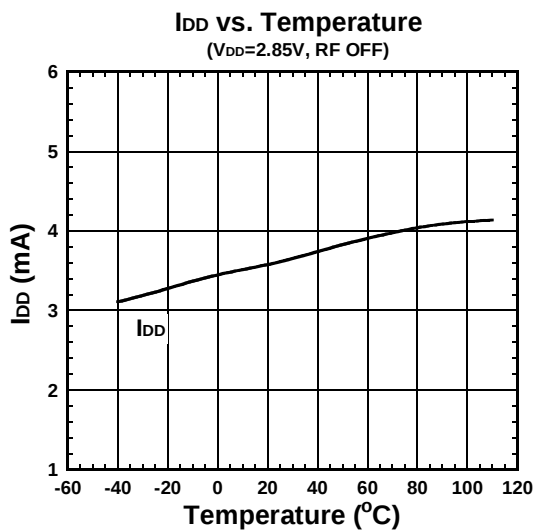
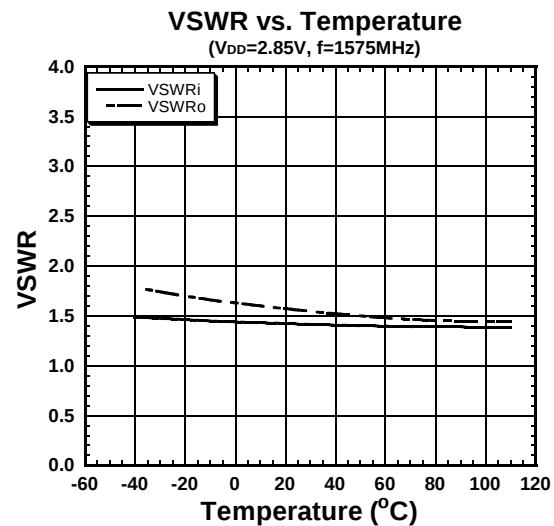
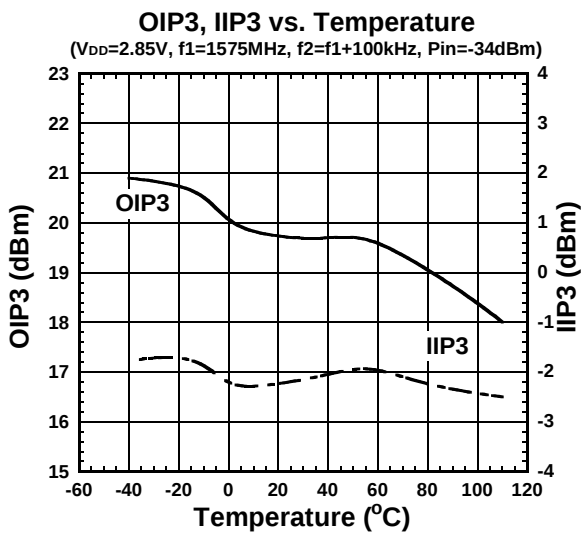
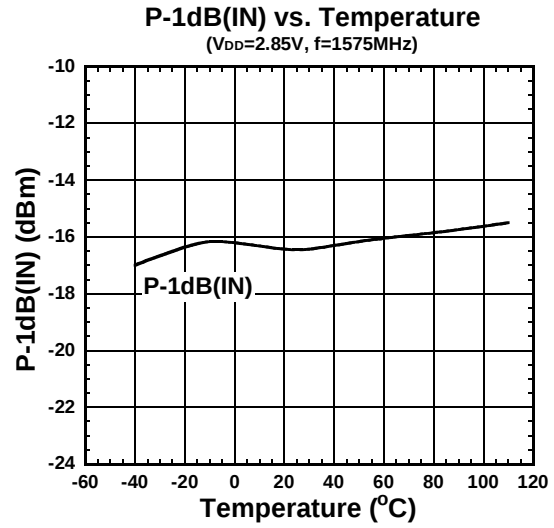
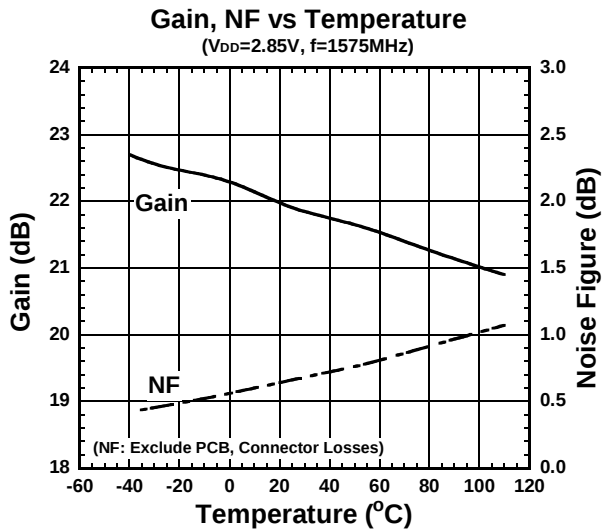
■ ELECTRICAL CHARACTERISTICS ($V_{DD}=2.85V$)

(Conditions: $T_a=+25^{\circ}C$, $V_{DD}=2.85V$, $Z_s=Z_l=50\Omega$, with application circuit.)



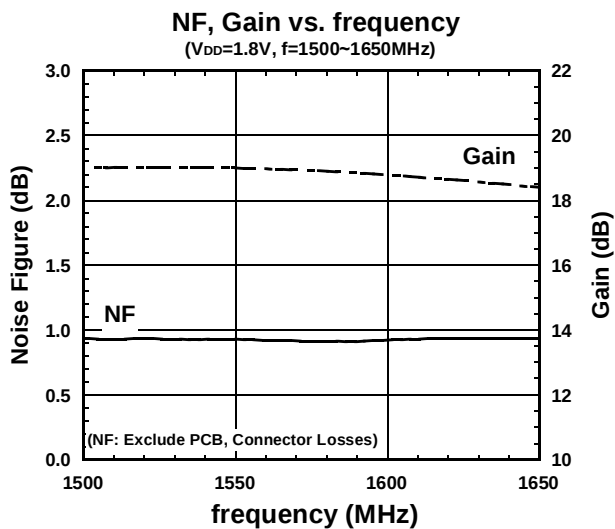
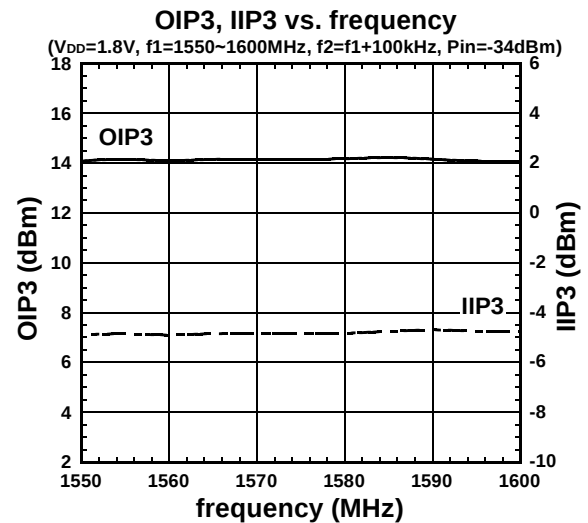
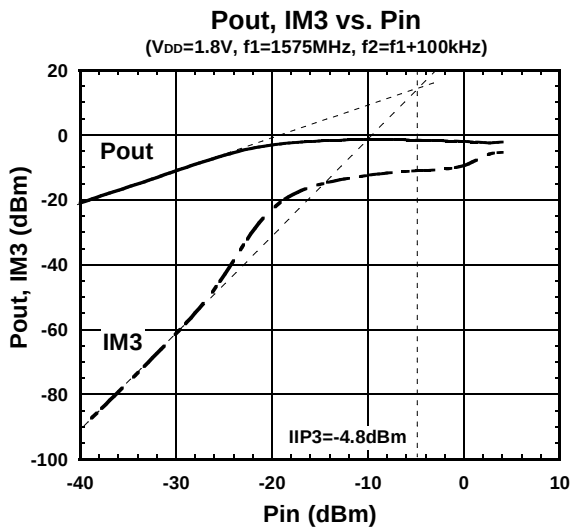
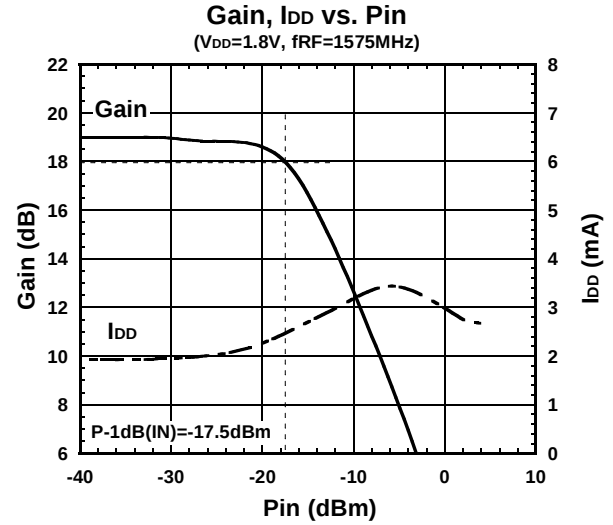
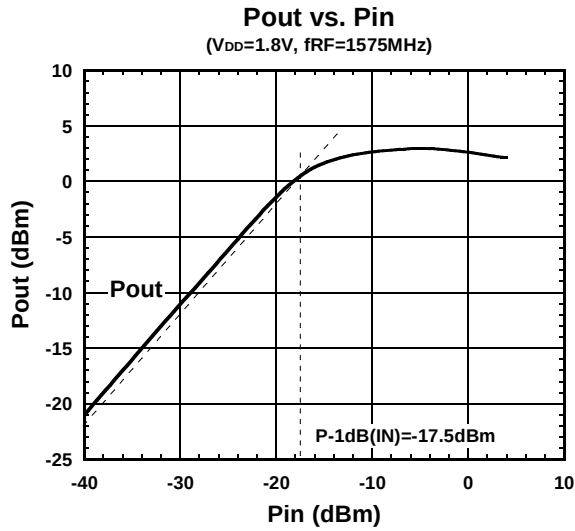
■ ELECTRICAL CHARACTERISTICS ($V_{DD}=2.85V$)

(Conditions: $V_{DD}=2.85V$, $Z_s=Z_l=50\Omega$, with application circuit.)



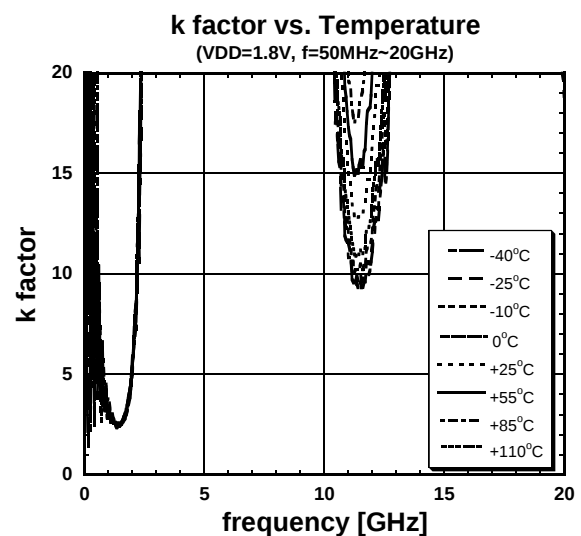
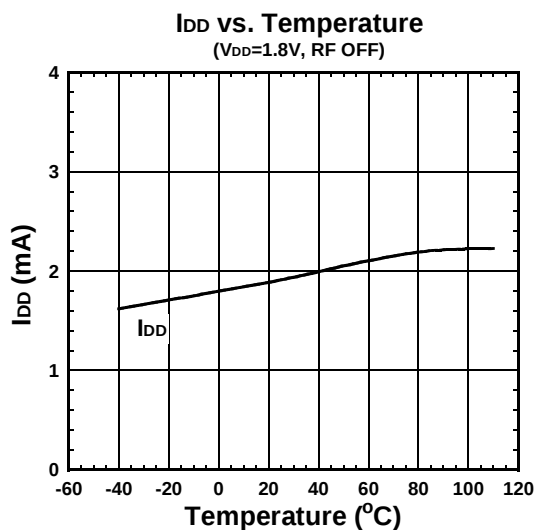
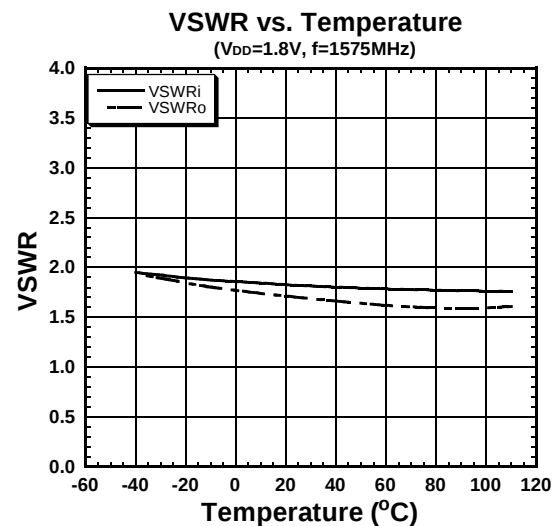
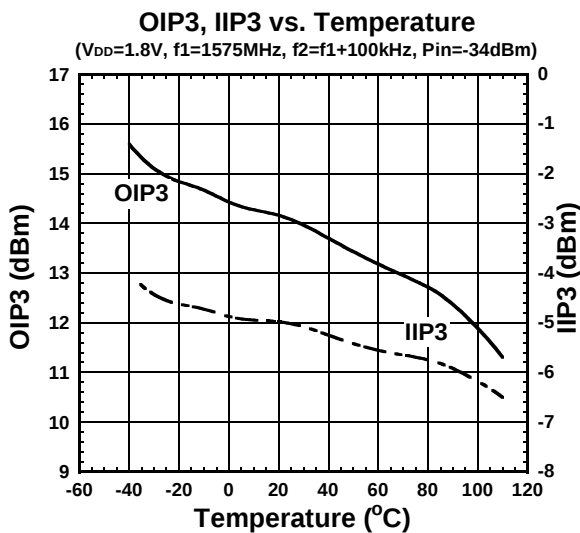
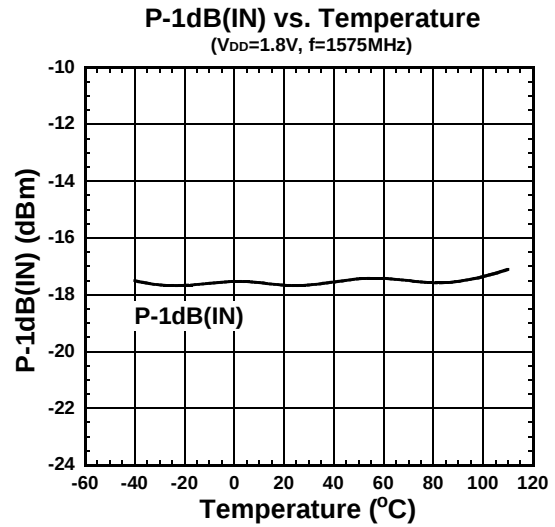
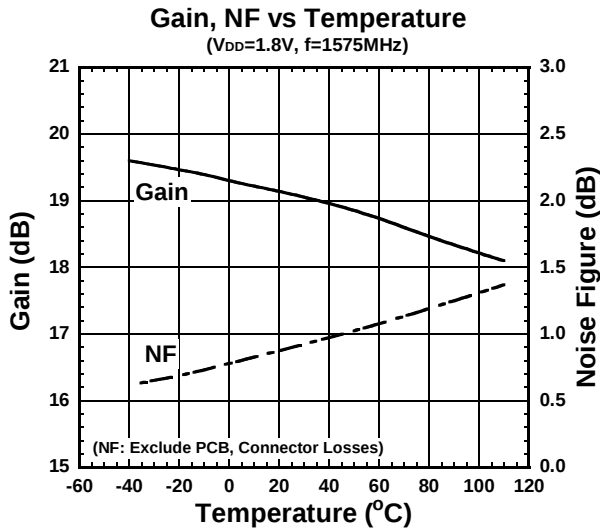
■ ELECTRICAL CHARACTERISTICS ($V_{DD}=1.8V$)

(Conditions: $T_a=+25^{\circ}C$, $V_{DD}=1.8V$, $Z_s=Z_l=50\Omega$, with application circuit.)



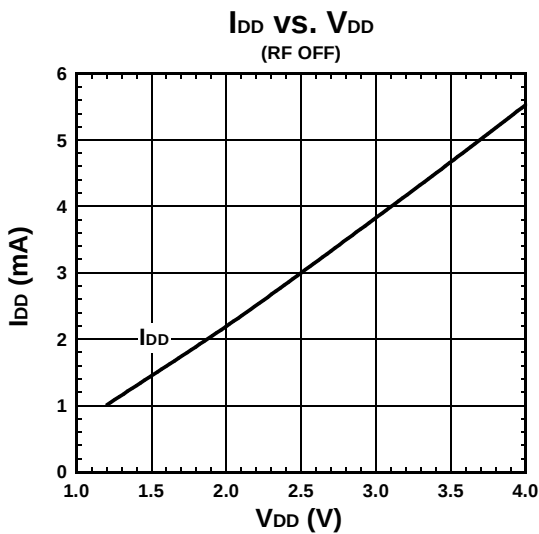
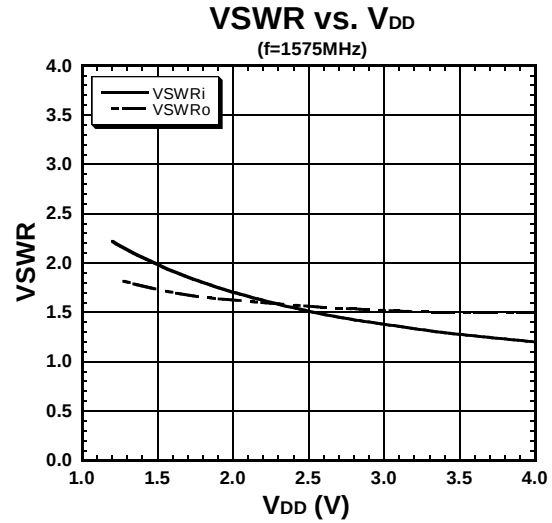
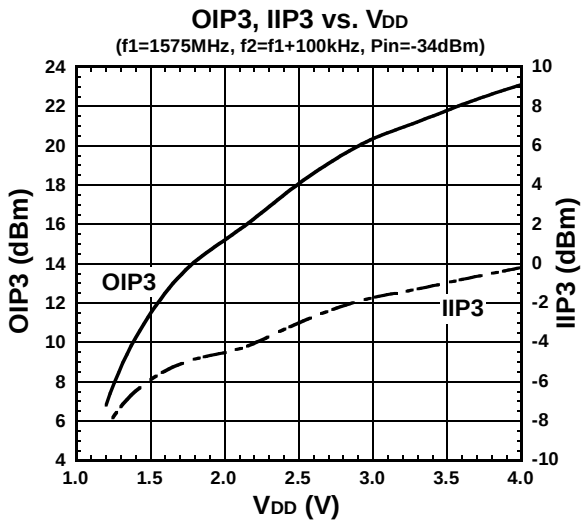
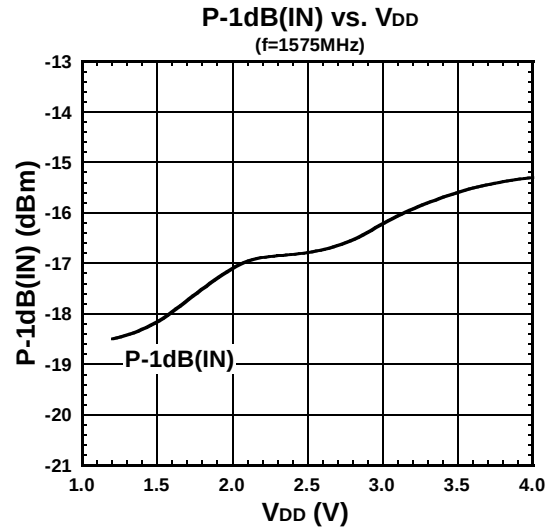
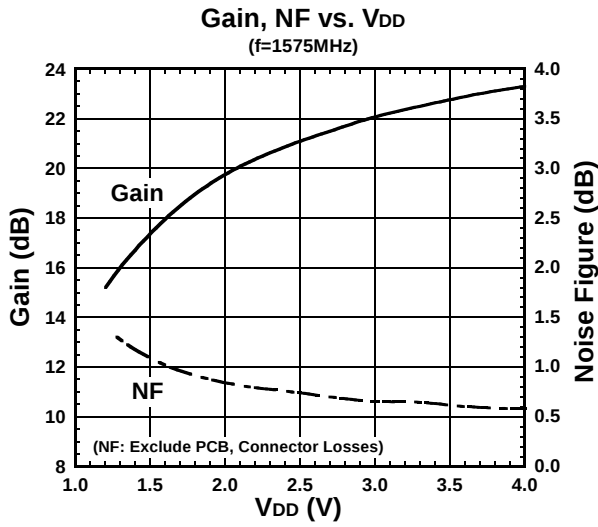
■ ELECTRICAL CHARACTERISTICS ($V_{DD}=1.8V$)

(Conditions: $V_{DD}=1.8V$, $Z_s=Z_l=50\Omega$, with application circuit.)



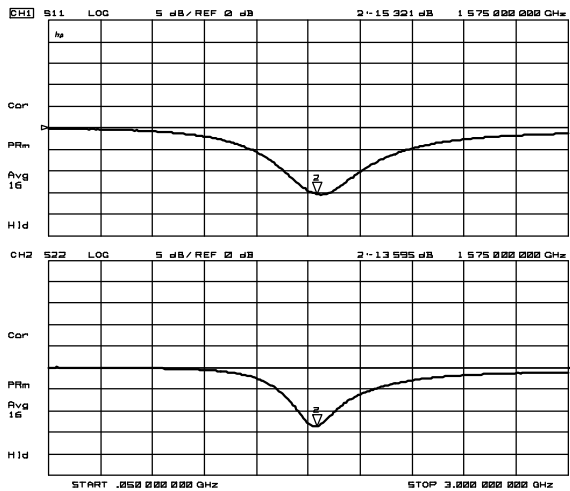
ELECTRICAL CHARACTERISTICS

(Conditions: $T_a = +25^\circ\text{C}$, $Z_s = Z_L = 50\Omega$, with application circuit.)

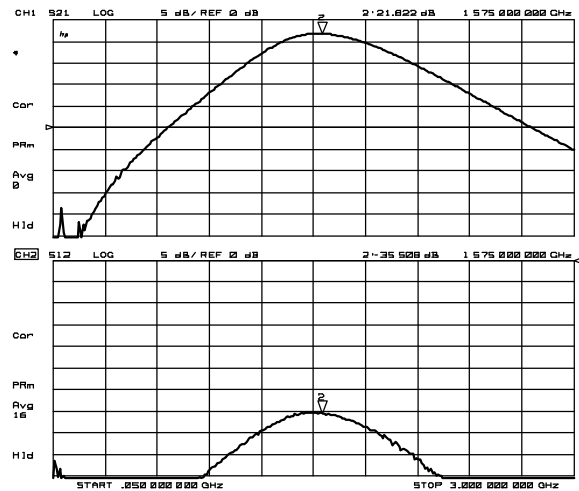


ELECTRICAL CHARACTERISTICS ($V_{DD}=2.85V$)

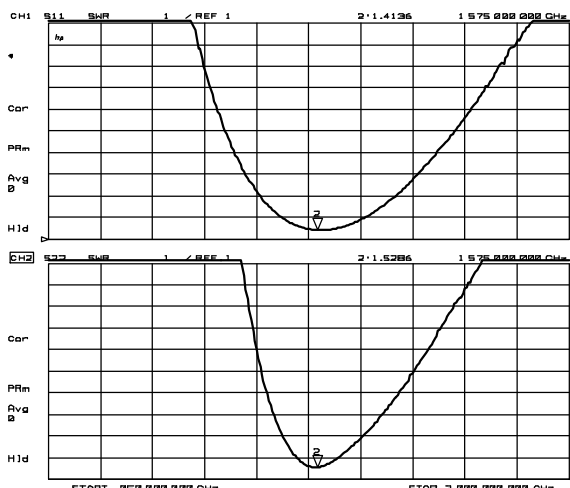
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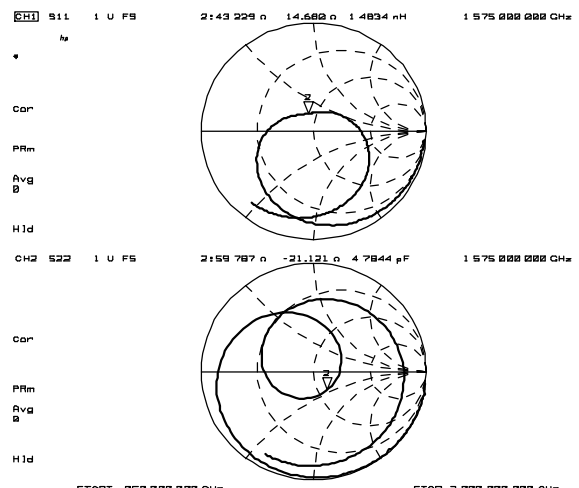
VSWR



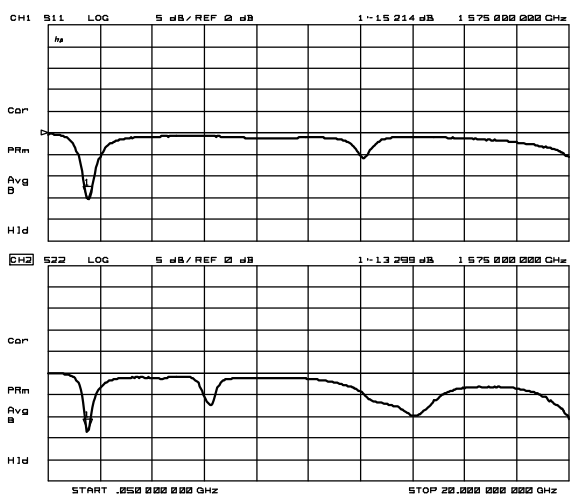
S21, S12



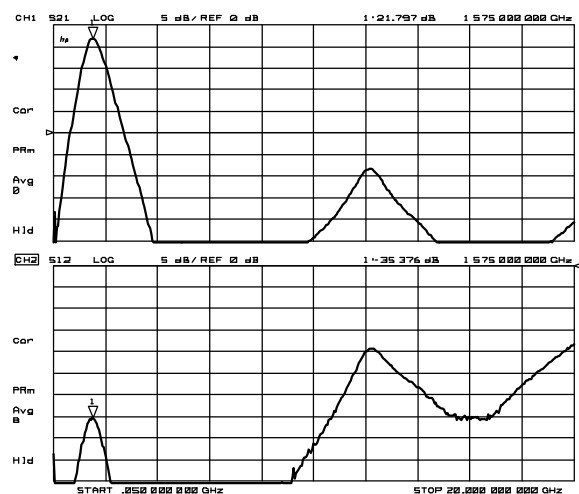
S11, S22



Zin, Zout



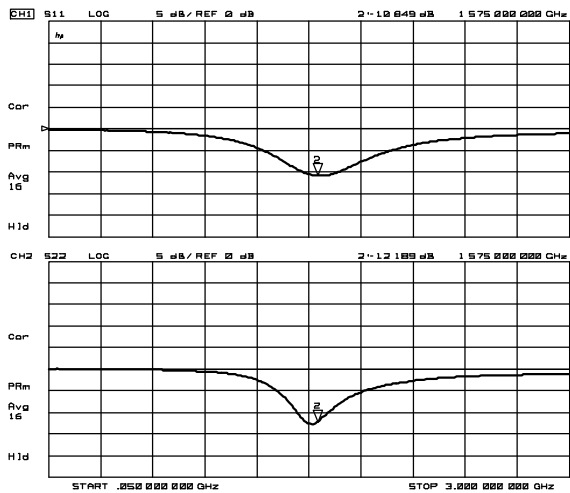
S11, S22 (50MHz to 20GHz)



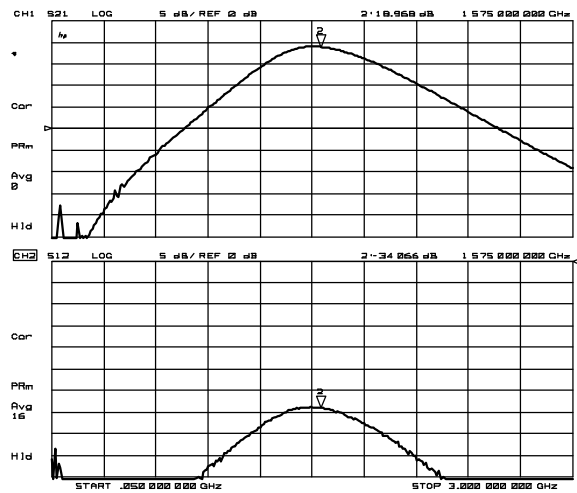
S21, S12 (50MHz to 20GHz)

ELECTRICAL CHARACTERISTICS ($V_{DD}=1.8V$)

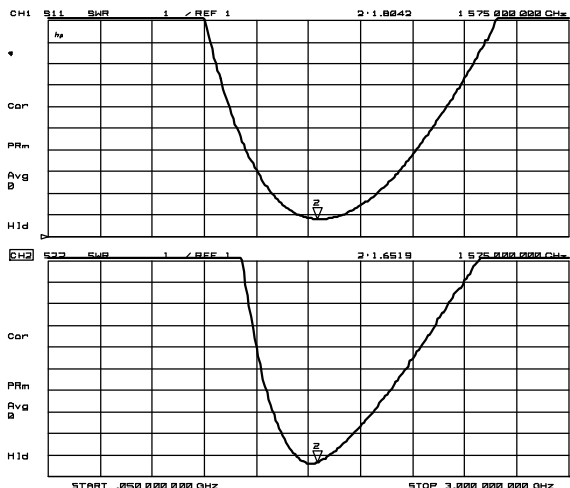
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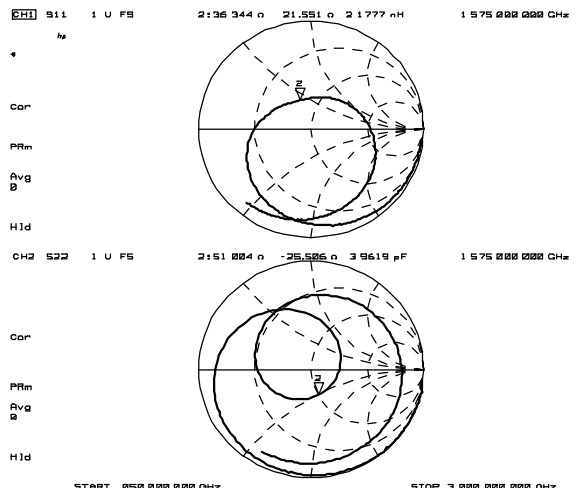
VSWR



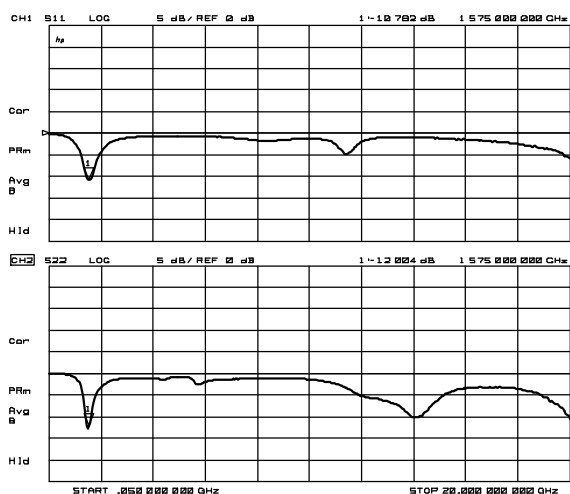
S21, S12



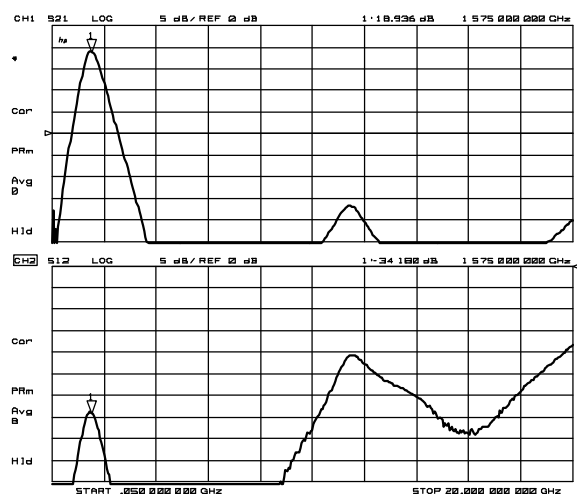
S11, S22



Zin, Zout

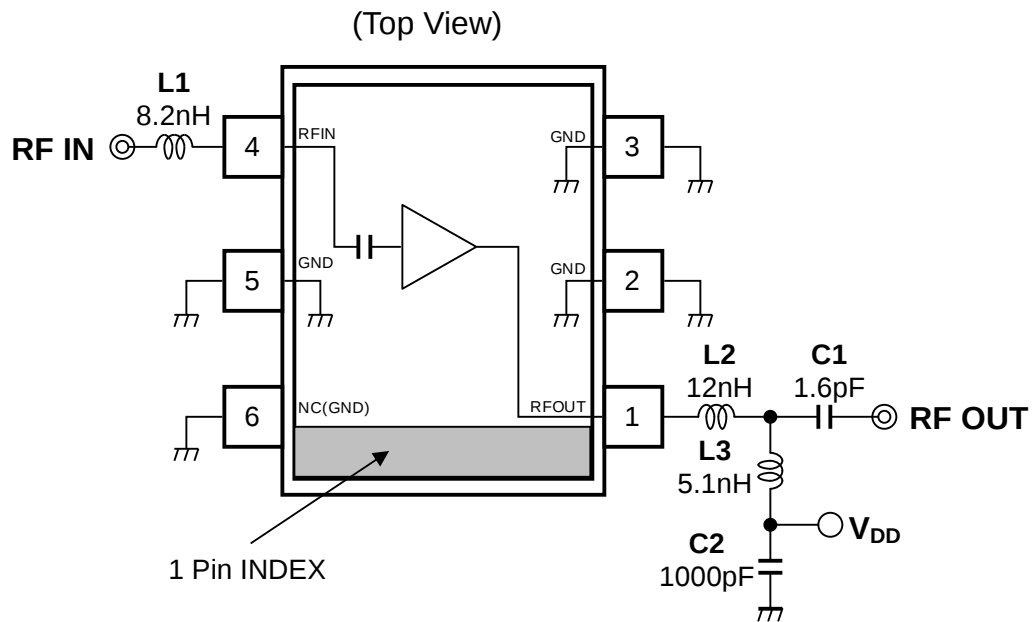


S11, S22 (50MHz to 20GHz)

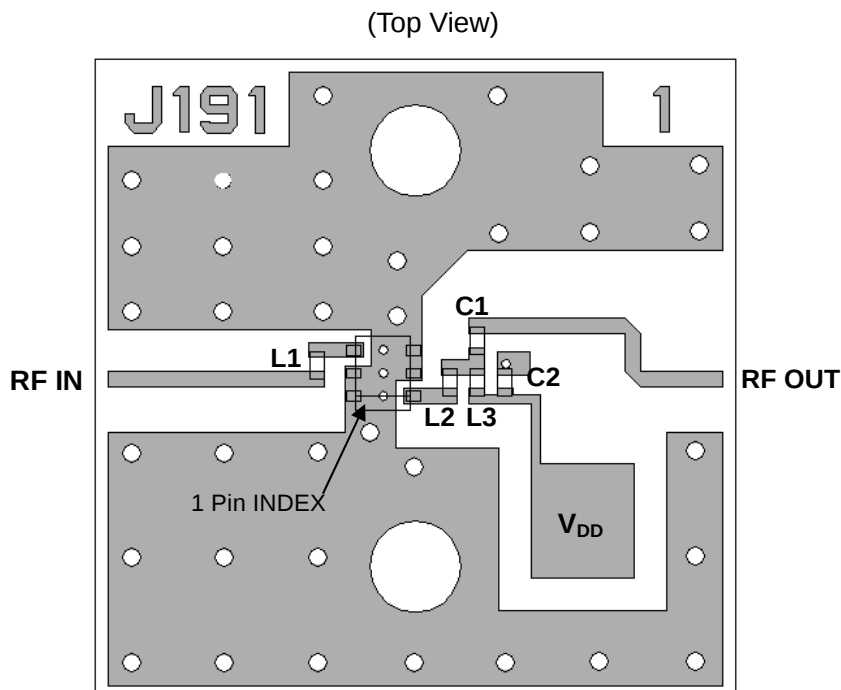


S21, S12 (50MHz to 20GHz)

APPLICATION CIRCUIT



TEST PCB LAYOUT



Parts list:

Parts ID	Comments
L1 to L3	MURATA LQP03T_02 Series
C1, C2	MURATA GRM03 Series

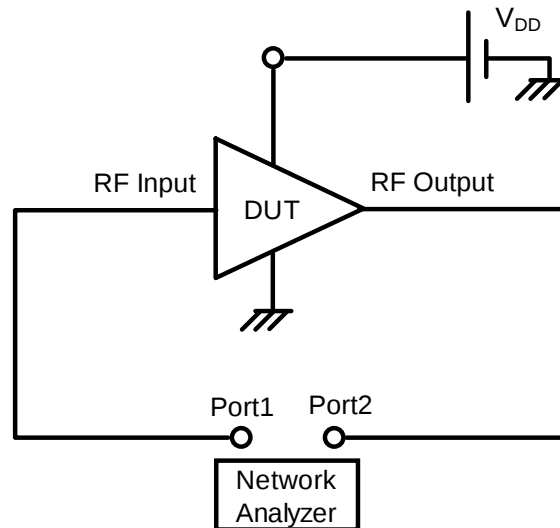
PCB (FR-4):
 $t=0.2\text{mm}$
 MICROSTRIP LINE WIDTH
 $=0.34\text{mm}$ ($Z_0=50\Omega$)
 PCB SIZE=14.0mm x 14.0mm

Caution:

In order not to couple with terminal RFIN and RFOUT, please layout ground pattern under the IC.

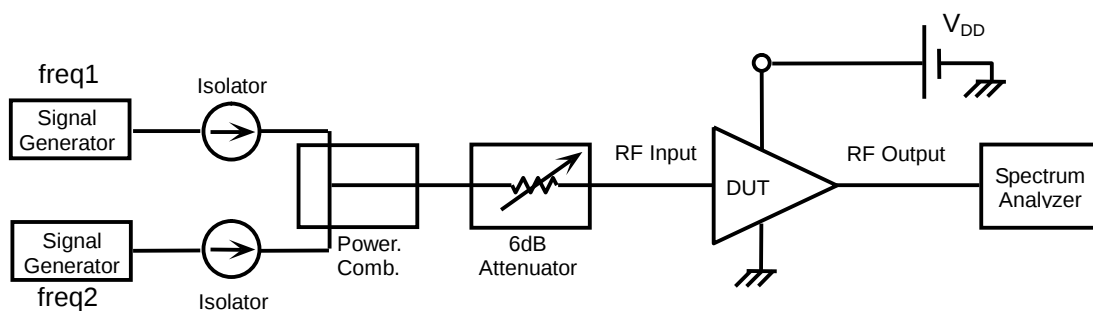
■ MEASUREMENT BLOCK DIAGRAM

- S parameter Measurements



S parameter Measurement Block Diagram

- IIP3 Measurements



IF and IM3 Measurement Block Diagram for IIP3

• Noise Figure Measurements

Measuring instruments

NF Analyzer : Agilent 8973A, 8975A
 Noise Source : Agilent 346A

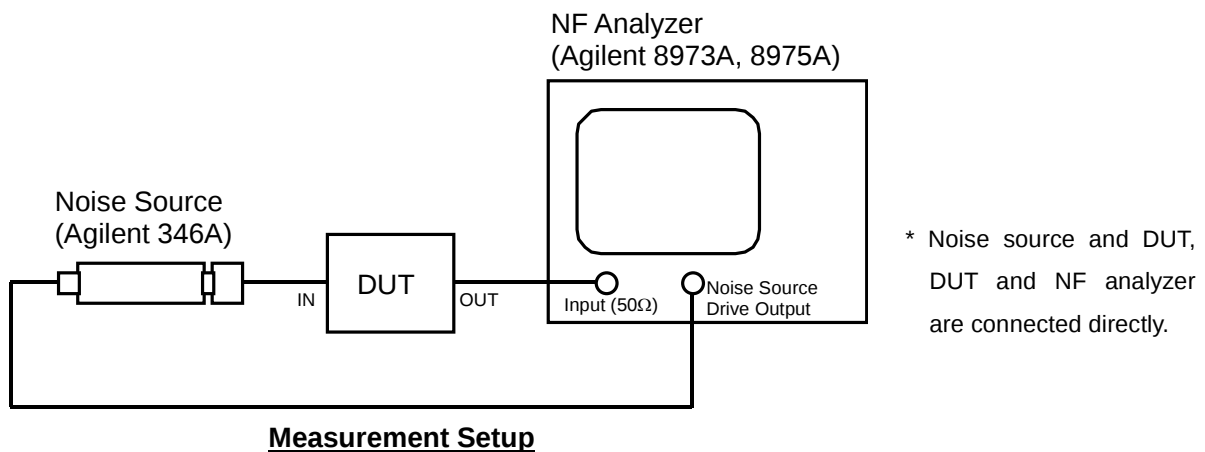
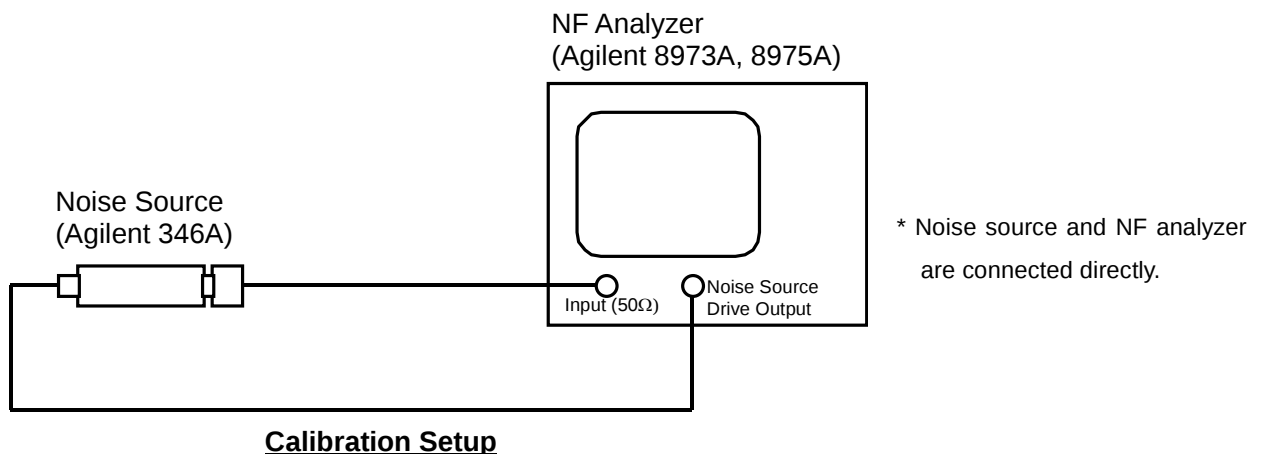
Setting the NF analyzer

Measurement mode form

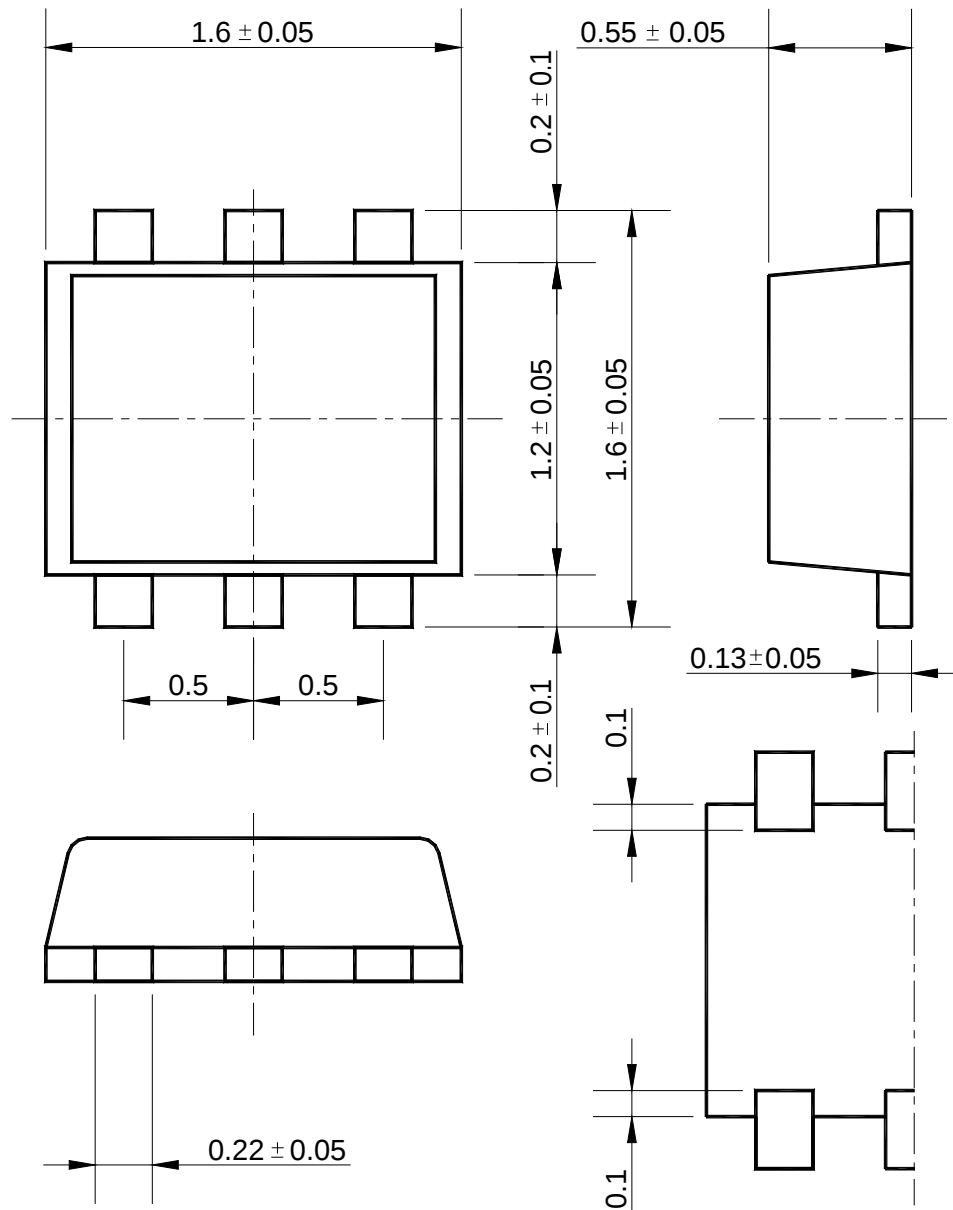
Device under test : Amplifier
 System downconverter : off

Mode setup form

Sideband : LSB
 Averages : 16
 Average mode : Point
 Bandwidth : 4MHz
 Loss comp : off
 Tcold : setting the temperature of noise source (303.15K)



■ PACKAGE OUTLINE (FLP6-A1)



Unit: mm

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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[NJG1144KA1-TE1](#)